GNSS Front-End Module

■ FEATURES

- AEC-Q100* grade 2
- Low supply voltage 2.8V typ.
- Low current consumption 3.7mA typ.
- High gain 16.0dB typ.
- Low noise figure

1.50dB typ. @f=1575MHz

1.65dB typ. @f=1597 to 1606MHz

1.70dB typ. @f=1559 to 1591MHz

High out band rejection

55dBc typ. @f=704 to 915MHz, relative to 1575MHz 43dBc typ. @f=1710 to 1980MHz, relative to 1575MHz 51dBc typ. @f=2400 to 2500MHz, relative to 1575MHz

- Integrated pre-SAW filter and LNA
- Small package size

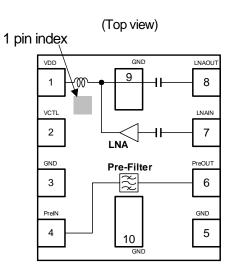
HFFP10-HH 1.5mmx1.1mm (typ.), t=0.5mm (max.)

• RoHS compliant and Halogen Free, MSL1

■ APPLICATION

- GNSS application for automotive
- •GNSS active antenna

■ BLOCK DIAGRAM (HFFP10-HH)



^{*} Please contact us for detail information regarding AEC-Q100.

■ GENERAL DESCRIPTION

The NJG1159PHH-A is a front-end module (FEM) designed for GNSS including GPS, GLONASS, BeiDou, and Galileo applications. This FEM offers low noise figure, high linearity, and high out-band rejection characteristics brought by included high performance pre-SAW filter and low noise amplifier (LNA). The stand-by mode contributes to reduce current consumption.

Its wide operating temperature range from -40 to +105°C is suitable for automotive application.

This FEM is suitable for small size application by included one SAW filter, only two external components, and very small package HFFP10-HH that is 1.5x1.1mm.

■ TRUTH TABLE

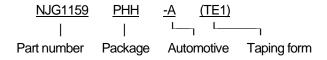
"H"=V_{CTL(H)}, "L"=V_{CTL(L)}

Vctl	Mode
Н	Active mode
L	Stand-by mode

■ PIN CONFIGURATION

PIN NO.	SYMBOL	DESCRIPTION
1	VDD	Supply voltage terminal
2	VCTL	Control voltage terminal
3	GND	Ground terminal
4	PrelN	RF input terminal to
4	PIEIN	Pre-SAW filter
5	GND	Ground terminal
6	PreOUT	RF output terminal from
	FIECUT	Pre-SAW filter
7	LNAIN	RF input terminal to LNA
8	LNAOUT	RF output terminal from LNA
9	GND	Ground terminal
10	GND	Ground terminal

■ PRODUCT NAME INFORMATION



■ ORDERING INFORMATION

PART NUMBER	PACKAGE OUTLINE	RoHS	HALOGEN- FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	QUANTITY PER REEL (pcs)
NJG1159PHH-A	HFFP10-HH	Yes	Yes	Au	59A	4.6	3,000

■ ABSOLUTE MAXIMUM RATINGS

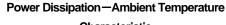
 $T_a=+25$ °C, $Z_s=Z=50\Omega$

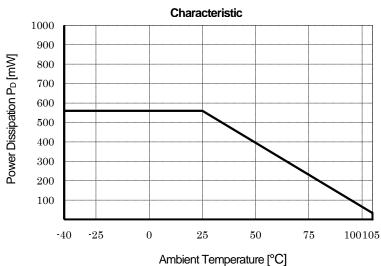
			-,
PARAMETER	SYMBOL	RATINGS	UNIT
Supply voltage	V_{DD}	5.0	V
Control voltage	Vctl	5.0	V
Input power	P _{IN} (inband) (1)	+10	dBm
	P _{IN} (outband) (2)	+25	dBm
Power dissipation	P _D ⁽³⁾	560	mW
Operating temperature	Topr	-40 to +105	°C
Storage temperature	T _{stg}	-40 to +110	°C

- (1): V_{DD}=2.8V, f=1575, 1597 to 1606, 1559 to 1591MHz
- (2): V_{DD} =2.8V, f=50 to 1460, 1710 to 4000MHz
- (3): 4-layer FR4 PCB without through-hole (101.5x114.5mm), T_j=110°C

■ POWER DISSIPATION VS.AMBIENT TEMPERATURE

Please note small non-lead package generally has low thermal dissipation characteristic, attention is recommended in designing of thermal radiation.





Nisshinbo Micro Devices Inc.

Automotive NJG1159PHH-A

■ ELECTRICAL CHARACTERISTICS 1 (DC)

(General conditions: T_a = 25°C, with application circuit)

PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{DD}		1.5	2.8	3.3	V
Control Voltage (High)	V _{CTL(H)}		1.5	1.8	3.3	V
Control Voltage (Low)	V _{CTL(L)}		0	0	0.3	V
Supply Current 1	I _{DD1}	RF OFF, V _{DD} =2.8V, V _{CTL} =1.8V	-	3.7	6.5	mA
Supply Current 2	I _{DD2}	RF OFF, V _{DD} =2.8V, V _{CTL} =0V	-	0.1	5.0	μA
Control Current	Iсть	V _{СП} =1.8V	-	5.0	15.0	μA

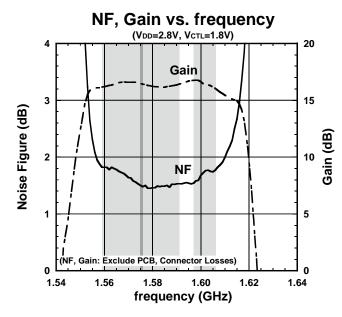
■ ELECTRICAL CHARACTERISTICS 2 (RF)

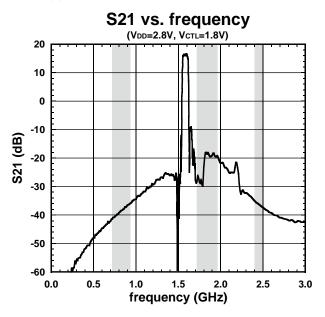
General conditions: V_{DD} =2.8V, V_{CTL} =1.8V, f_{RF} =1575MHz, 1597 to 1606MHz, 1559 to 1591MHz, T_a =+25°C, Z_s =Z=50 Ω , with application circuit

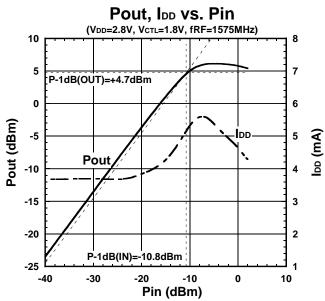
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Small Signal Gain	GainGPS	f=1575MHz (GPS)	13.5	16.0	_	dB
(GPS)	Cairioi C	Exclude PCB, Connector Losses (0.17dB)	10.0	10.0		u.b
Small Signal Gain	GainGLN	f=1597 to 1606MHz (GLONASS)	13.0	16.5	-	dB
(GLONASS)	Galliotiv	Exclude PCB, Connector Losses (0.17dB)	10.0	10.0		
Small Signal Gain	GainBG	f=1559 to 1591MHz (BeiDou, Galileo)	13.0	16.0	_	dB
(BeiDou, Galileo)	GairibG	Exclude PCB, Connector Losses (0.17dB)	13.0	10.0	-	uБ
Noise Figure	NFGPS	f=1575MHz (GPS)Exclude PCB,		1.50	2.35	dB
(GPS)	NEGES	Connector Losses (0.09dB)	-	1.50		
Noise Figure	NFGLN	f=1597 to 1606MHz (GLONASS)		1.65	2.70	dB
(GLONASS)	INFGLIN	Exclude PCB, Connector Losses (0.09dB)	-			
Noise Figure	NFBG	f=1559 to 1591MHz (BeiDou, Galileo)		1.70	2.80	dB
(BeiDou, Galileo)	INFBG	Exclude PCB, Connector Losses (0.09dB)	-			
Input Power at 1dB Gain	D 1dD(INI)	f=1575,	15.0	-10.0		dBm
Compression Point	P-1dB(IN)	1597 to 1606, 1559 to 1591MHz	-15.0	-10.0	_	UDIII
Low Pand Paiastian	DD I	f=704 to 915MHz,	41	55		dBc
Low Band Rejection	BR_L	relative to 1575MHz	41	55	_	
High Bond Boingtion	DD LI	f=1710 to 1980MHz,	23	40		dDo
High Band Rejection	BR_H	relative to 1575MHz	23	43	_	dBc
MI AN Dand Dejection	DD W	f=2400 to 2500MHz,	38	51	-	dBc
WLAN Band Rejection	BR_W	relative to 1575MHz	38			

■ ELECTRICAL CHARACTERISTICS

Conditions: V_{DD} =2.8V, V_{CTL} =1.8V, Ta=25°C, Z_s = Z_l =50 Ω , with application circuit

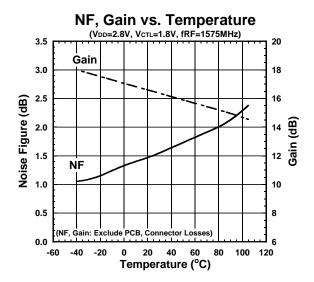


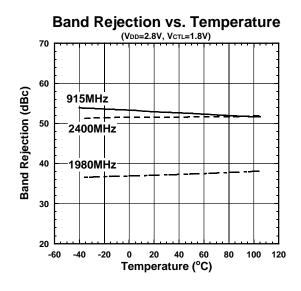


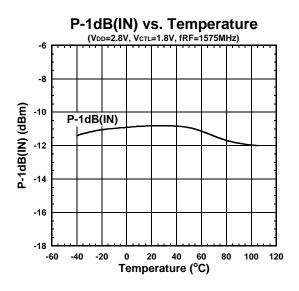


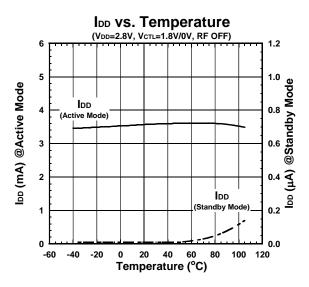
■ ELECTRICAL CHARACTERISTICS

Conditions: V_{DD} =2.8V, V_{CTL} =1.8V, Z_s = Z_l =50 Ω , with application circuit



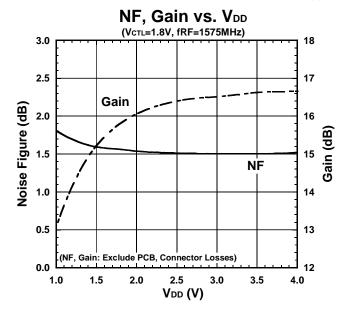


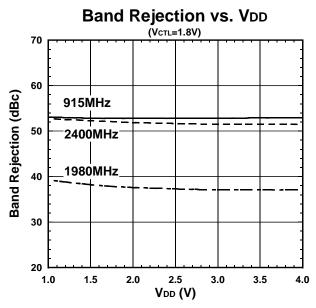


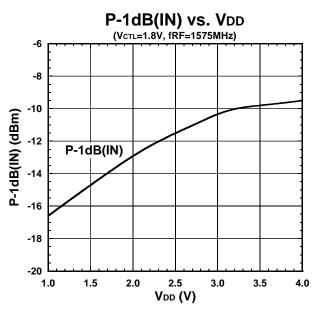


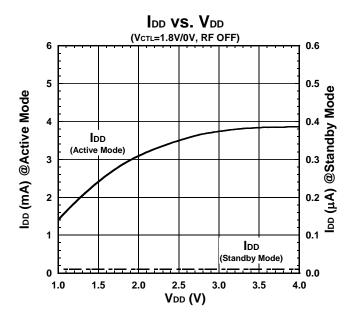
■ ELECTRICAL CHARACTERISTICS

Conditions: $V_{CTL}=1.8V$, Ta=25°C, $Z_s=Z_l=50\Omega$, with application circuit

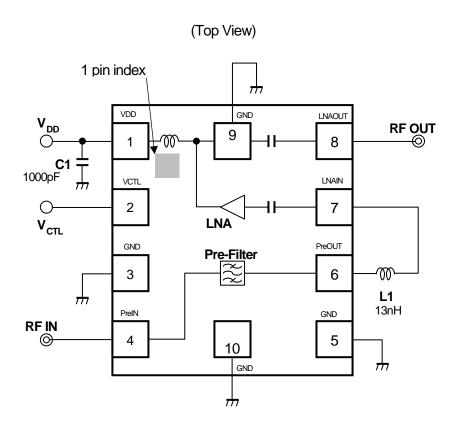








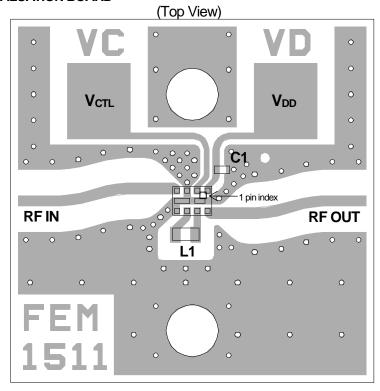
■ APPLICATION CIRCUIT



<PARTS LIST>

Part ID	Note	
L1	LQW15AN_00 Series	
	(MURATA)	
C1	GRM03 Series	
	(MURATA)	

■ EVALUATION BOARD



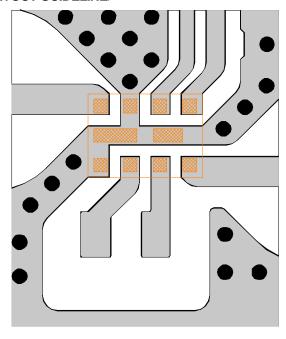
PCB

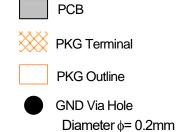
Substrate: FR-4 Thickness: 0.2mm

Microstrip line width: 0.4mm ($Z_0=50\Omega$)

Size: 14.0mm x 14.0mm

<PCB LAYOUT GUIDELINE>





PRECAUTIONS

- Please layout ground pattern under this FEM in order not to couple with RFIN and RFOUT terminal.
- All external parts should be placed as close as possible to the FEM.
- For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the FEM.

■ HANDLING PRECAUTIONS

PIN NO. SYMBOL		ESD RATINGS				
PIN NO.	STIVIBUL		HBM ⁽³⁾		CDM ⁽⁴⁾	
Common terminal		Ground	VDD	I/O	CDIVI	
1	VDD	Class 2	COM.	-	Class C3	
2	VCTL	Class 2	Class 2	Class 2	Class C3	
3	GND	COM.	Class 2	-	Class C3	
4	PrelN	Class 0B	Class 0B	Class 0B	Class C3	
5	GND	COM.	Class 2	-	Class C3	
6	PreOUT	Class 0B	Class 0B	Class 0B	Class C3	
7	LNAIN	Class 2	Class 2	Class 1C	Class C3	
8	LNAOUT	Class 2	Class 2	Class 2	Class C3	
9	GND	COM.	Class 2	-	Class C3	
10	GND	COM.	Class 2	-	Class C3	

^{(4):} Human Body Model according to JEDEC JS-001, (5): Charged Device Model according to JEDEC JS-002

CAUTION: This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

■ NOISE FIGURE MEASUREMENT BLOCK DIAGRAM

Measuring instruments

NF Analyzer : Keysight N8973A Noise Source : Keysight 346A

Setting the NF analyzer

Measurement mode form

Device under test : Amplifier
System downconverter : off

Mode setup form

Sideband : LSB

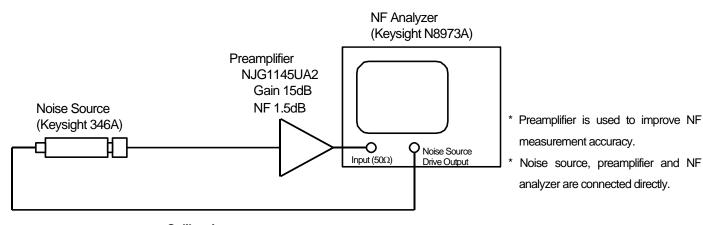
Averages : 16

Average mode : Point

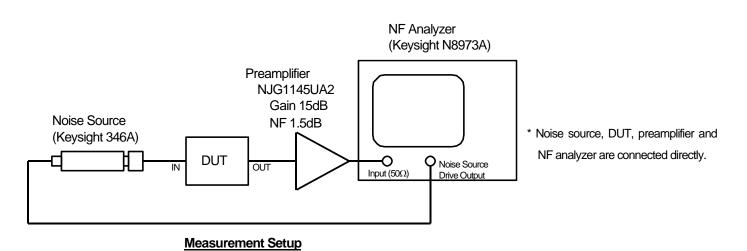
Bandwidth : 4MHz

Loss comp : off

Tcold : setting the temperature of noise source (303.15K)







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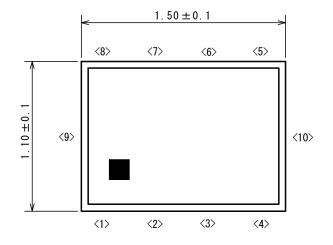
■ REVISION HISTORY

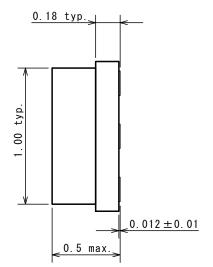
Date	Revision	Changes	
15.Nov.2016	Ver.1.0	New Release Automotive spec	
		Changed package suffix from H to A	
19.Jul.2017	Ver.1.1	Updated ELECTRICAL CHARACTERISTICS 1 (DC)	
19.Jul.2017	vei.i.i	Updated ELECTRICAL CHARACTERISTICS 2 (RF)	
		Added packing specification	
19.Oct.2018	Ver.1.2	Revised features	
19.00.2016	Vel.1.2	Revised caution	
		Revised MARK INFORMATION	
08.Nov.2018	Ver.1.3	Revised ORDERING INFORMATION	
		Revised weight	
		Revised features	
		Added APPLICATION	
		Revised PRODUCT NAME INFORMATION	
08.Jan.2019	Ver.1.4	Revised ORDERING INFORMATION	
		Revised ELECTRICAL CHARACTERISTICS 2 (RF)	
		Added POWER DISSIPATION VS.AMBIENT TEMPERATURE	
		Revised caution	
		Revised features	
		Revised ORDERING INFORMATION	
07.Feb.2024	Ver.1.5	Added HANDLING PRECAUTIONS	
01.FED.2024	V CI. 1.3	Revised PACKAGE DIMENSIONS	
		Revised EXAMPLE OF SOLDER PADS DIMENSIONS	
		Revised PACKING SPEC	

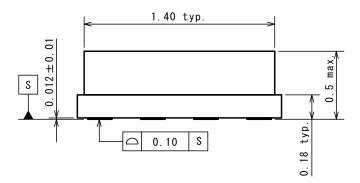
HFFP10-HH
PI-HFFP10-HH-E-A

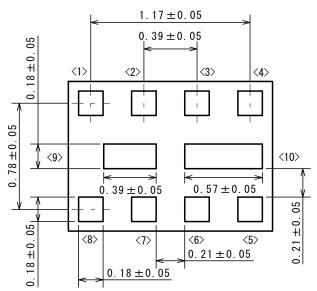
■ PACKAGE DIMENSIONS

UNIT: mm







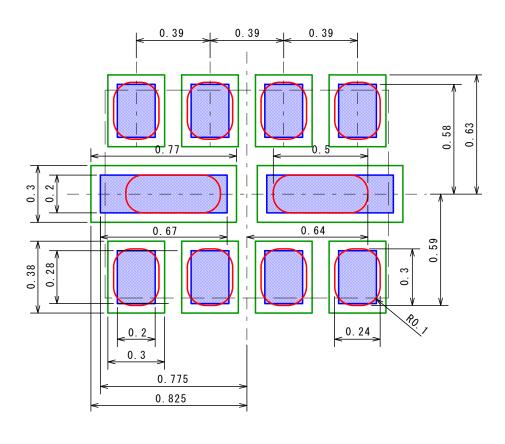




HFFP10-HH PI-HFFP10-HH-E-A

■ EXAMPLE OF SOLDER PADS DIMENSIONS

UNIT: mm



: Land

: Mask (Open area) Metal mask thickness : $100\,\mu\,\mathrm{m}$

: Resist (Open area)

: Package outline



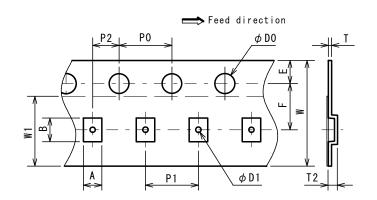
Nisshinbo Micro Devices Inc.

HFFP10-HH
PI-HFFP10-HH-E-A

■ PACKING SPEC

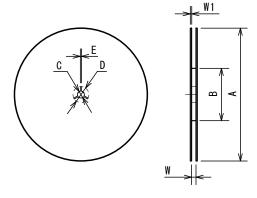
TAPING DIMENSIONS





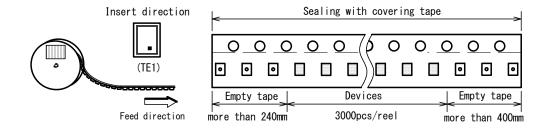
SYMBOL	DIMENSION	REMARKS
A	1.4±0.1	BOTTOM DIMENSION
В	1.8±0.1	BOTTOM DIMENSION
D0	1. 5 +0.1	
D1	0.5±0.05	
E	1.75±0.1	
F	3.5±0.05	
P0	4.0±0.1	
P1	4.0±0.1	
P2	2.0±0.05	
T	0.25 ± 0.05	
T2	0.7±0.1	
W	8.0±0.2	
W1	5.3±0.2	THICKNESS100 μ m max

REEL DIMENSIONS

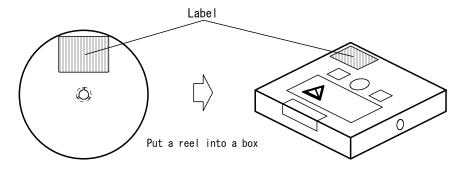


SYMBOL	DIMENSION	
A	ϕ 180 $^{0}_{-1.5}$	
В	φ 66±0.5	
С	φ 13±0.2	
D	φ 21±0.8	
Е	2±0.5	
W	9 +1	
W1	1. 2	

TAPING STATE



PACKING STATE





- 1. The products and the product specifications described in this document are subject to change or discontinuation of production without notice for reasons such as improvement. Therefore, before deciding to use the products, please refer to our sales representatives for the latest information thereon.
- 2. The materials in this document may not be copied or otherwise reproduced in whole or in part without the prior written consent of us.
- 3. This product and any technical information relating thereto are subject to complementary export controls (so-called KNOW controls) under the Foreign Exchange and Foreign Trade Law, and related politics ministerial ordinance of the law. (Note that the complementary export controls are inapplicable to any application-specific products, except rockets and pilotless aircraft, that are insusceptible to design or program changes.) Accordingly, when exporting or carrying abroad this product, follow the Foreign Exchange and Foreign Trade Control Law and its related regulations with respect to the complementary export controls.
- 4. The technical information described in this document shows typical characteristics and example application circuits for the products. The release of such information is not to be construed as a warranty of or a grant of license under our or any third party's intellectual property rights or any other rights.
- 5. The products listed in this document are intended and designed for automotive applications. Those customers intending to use a product in an application requiring extreme quality and reliability, for example, in a highly specific application where the failure or misoperation of the product could result in human injury or death should first contact us.
 - · Aerospace Equipment
 - · Equipment Used in the Deep Sea
 - Power Generator Control Equipment (nuclear, steam, hydraulic, etc.)
 - Life Maintenance Medical Equipment
 - · Fire Alarms / Intruder Detectors
 - Vehicle Control Equipment (airplane, railroad, ship, etc.)
 - Various Safety Devices
 - Traffic control system
 - Combustion equipment

In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.

- 6. We are making our continuous effort to improve the quality and reliability of our products, but electronic device products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
 - 8-1. Quality Warranty Period

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.

8-2. Quality Warranty Remedies

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.

8-3. Remedies after Quality Warranty Period

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.

- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 12. Front end module product is hollow seal package type, and it is with the structure susceptible to stress from the outside. Therefore, note the following in relation to the contents, after conducting an evaluation. please use.
 - 12-1. After mounting this product, to implement the potting and transfer molding, please the confirmation of resistance to temperature changes and shrinkage stress involved in the molding.
 - 12-2. When mounted on the product, collet diameter please use more than 1mmφ. In addition, the value of static load is recommended mounting less than 5N.
 - 12-3. For dynamic load at the time of mounting. please use it after confirming in consideration of the contact area /speed /load.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



Official website

https://www.nisshinbo-microdevices.co.jp/en/

Purchase information

https://www.nisshinbo-microdevices.co.jp/en/buy/